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# ETRX358x ZIGBEE® MODULES PRODUCT MANUAL





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The Telegesis ETRX358x and ETRX358xHR series modules are small outline, low power 2.4GHz ZigBee modules, based on the latest Silicon Labs EM358x family of single chip ZigBee® solutions.

These 4<sup>th</sup> generation modules have been designed to be integrated into any device without the need for RF experience and expertise. Utilizing the market's premier EmberZNet ZigBee® stack, the ETRX358x series enables you to add powerful wireless networking capability to your products and quickly bring them to market.

For custom application development the ETRX358x series integrates with ease into Ember Desktop development environment.

#### **Module Features**

- Small form factor, SMT module 25mm x 19mm
- · Same footprint and pin-out as ETRX357
- Side Castellations for easy soldering and optical inspection
- Two antenna options: Integrated chip antenna or U.FL coaxial connector
- Based on 32-bit ARM® Cortex-M3
- Operation at 6, 12 or 24MHz
- Industry standard JTAG Programming and real time packet tracing via the Ember Debug Port
- Up to 512kB of flash and 64kbytes of RAM
- Lowest Deep Sleep Current of 1μA with retained RAM and GPIO and multiple sleep modes
- Wide supply voltage range (2.1 to 3.6V)
- Optional 32.768kHz watch crystal can be added externally
- · Can act as an End Device, Router or Coordinator
- 24 general-purpose I/O lines including analogue inputs (all GPIOs of the EM358x SoC are accessible)
- Firmware upgrades via serial port or over the air using the Ember standalone bootloader
- Hardware supported encryption (AES-128)
- CE, FCC and IC compliance, FCC modular approval
- Operating temperature range: -40°C to +85°C
- Long range version with a link budget of up to 124dB available in the same form factor

#### **Suggested Applications**

- ZigBee Smart Energy applications
- · Wireless Alarms and Security
- Home/Building Automation
- Wireless Sensor Networks
- M2M Industrial Controls
- · Lighting and ventilation control
- · Remote monitoring
- · Environmental monitoring and control

#### **Development Kit**

- ETRX3587 Expansion Pack for ETRX357 Development Kit
- ETRX357 Development kit containing everything required to set up a mesh network quickly and evaluate range and performance of the ETRX357 series and its long-range version.
- Custom software development available upon request.

#### **Radio Features**

- Based on the Silicon Labs EM358x family of single chip ZigBee® SoCs
- 2.4GHz ISM Band
- 250kbit/s over the air data rate
- 16 channels (IEEE802.15.4 Channel 11 to 26)
- +3dBm output power ( +8dBm in boost mode)
- High sensitivity of -100dBm (-102dBm in boost mode) typically @ 1% packet error rate
- RX Current: 27mA, TX Current: 32mA at 3dBm
- Robust Wi-Fi and Bluetooth coexistence



#### 1 Introduction

This document describes the Telegesis ETRX358x and ETRX358xHR family of ZigBee modules which have been designed to be easily integrated into another device and to provide a fast, simple and low cost wireless mesh networking interface.

The Telegesis ETRX3 series modules are based on the Silicon Labs ZigBee compliant platform consisting of the single chip family of EM358x SoCs combined with the ZigBee PRO compliant EmberZNet meshing stack. The ETRX358x and ETRX358xHR modules represent an ideal platform for custom firmware development in conjunction with the Silicon Labs ZigBee development kits.

No RF experience or expertise is required to add this powerful wireless networking capability to your products. The ETRX358x and ETRX358xHR series of modules offer fast integration opportunities and the shortest possible time to market for your product.

#### 1.1 Hardware Description

The main building blocks of the ETRX358x and ETRX358xHR modules are the single chip EM358x SoC from Silicon Labs, a 24MHz reference crystal and RF front-end circuitry optimized for best RF performance. The modules are available with on-board antenna or alternatively a U.FL coaxial connector for attaching external antennae. Modules with the U.FL connector are identified by the "HR" suffix.

The integrated antenna is an Antenova Rufa, and details of the radiation pattern are available from the Antenova website [5].

Module	Chip	Flash	RAM	Antenna	USB
ETRX35811	EM3581	256kB	32kB	Chip	No
ETRX3581HR <sup>1</sup>	EM3581	256kB	32kB	External	No
ETRX3582 <sup>1</sup>	EM3582	256kB	32kB	Chip	Yes
ETRX3582HR <sup>1</sup>	EM3582	256kB	32kB	External	Yes
ETRX3585 <sup>1</sup>	EM3585	512kB	32kB	Chip	No
ETRX3585HR <sup>1</sup>	EM3585	512kB	32kB	External	No
ETRX3586 <sup>1</sup>	EM3586	512kB	32kB	Chip	Yes
ETRX3586HR <sup>1</sup>	EM3586	512kB	32kB	External	Yes
ETRX3587	EM3587	512kB	64kB	Chip	No
ETRX3587HR	EM3587	512kB	64kB	External	No
ETRX3588 <sup>1</sup>	EM3588	512kB	64kB	Chip	Yes
ETRX3588HR <sup>1</sup>	EM3588	512kB	64kB	External	Yes

**Table 1: Module Variants** 

The ETRX358x and ETRX358xHR are used for ZigBee (<u>www.zigbee.org</u>) applications. In case it is desired to develop custom firmware, the Silicon Labs toolchain, consisting of Ember Desktop together with a comprehensive integrated development environment (IDE), is required.

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<sup>&</sup>lt;sup>1</sup> MOQ and Lead Time applies. Only stocked modules are ETRX3587 and ETRX3587HR



## 2 Product Approvals

The ETRX358x and ETRX358xHR have been designed to meet all national regulations for world-wide use. In particular the following certifications have been obtained:

#### 2.1 FCC Approvals

The Telegesis ETRX358x family integrated Antenna as well as the ETRX358xHR family including the antennas listed in Table 2 and the power levels listed in section 10.2 have been tested to comply with FCC CFR Part 15 (USA) The devices meet the requirements for modular transmitter approval as detailed in the FCC public notice DA00.1407.transmitter.

#### FCC statement:

This device complies with Part 15 of the FCC rules. Operation is subject to the following two conditions: (1) this device may not cause harmful interference, and (2) this device must accept any interference received, including interference that may cause undesired operation.



FCC ID: S4GEM358X

This module is approved for use in both portable and mobile applications. The module and associated antenna must be installed to provide a separation distance of at least 0.75cm from all persons and must not transmit simultaneously with any other antenna or transmitter.

Item	Part No.	Manufacturer	Туре	Impedance	Gain
1	BT-Stubby (straight)	EAD Ltd. [6]	1/4 Wave	50Ω	0dBi
2	BT-Stubby (right-angle)	EAD Ltd. [6]	1/4 Wave	50Ω	0dBi
3	CJ-2400-6603	Chang Jia	½ Wave	50 Ω	2.0dBi
4	Rufa (on board)	Antenova	Chip	50Ω	2.1dBi (peak)

**Table 2: Approved Antennae** 

While the applicant for a device into which the ETRX358x or ETRX358xHR with an antenna listed in Table 2 is installed is not required to obtain a new authorization for the module, this does not preclude the possibility that some other form of authorization or testing may be required for the end product depending upon local territorial regulations.

The FCC requires the user to be notified that any changes or modifications made to this device that are not expressly approved by Telegesis (UK) Ltd. may void the user's authority to operate the equipment.

When using the ETRX358xHR family with approved antennae, it is required to prevent end-users from replacing them with non-approved ones.



## 2.1.1 FCC Labelling Requirements

When integrating the ETRX358x or ETRX358xHR families into a product it must be ensured that the FCC labelling requirements are met. This includes a clearly visible label on the outside of the finished product specifying the Telegesis FCC identifier (FCC ID: S4GEM358X) as well as the FCC notice shown on the previous page. This exterior label can use wording such as "Contains Transmitter Module FCC ID: S4GEM358X" or "Contains FCC ID: S4GEM358X" although any similar wording that expresses the same meaning may be used.

## 2.2 IC (Industry Canada) Approvals

The Telegesis ETRX358x family with integrated Antenna as well as the ETRX358xHR family have been approved by Industry Canada to operate with the antenna types listed in Table 2 with the maximum permissible gain and required antenna impedance for each antenna type indicated. Antenna types not included in this list, having a gain greater than the maximum gain indicated for that type, are strictly prohibited for use with this device.

IC-ID: 8735A-EM358X

- This device complies with Industry Canada license-exempt RSS standard(s).
   Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.
- Under Industry Canada regulations, this radio transmitter may only operate using an antenna of a type and maximum (or lesser) gain approved for the transmitter by Industry Canada. To reduce potential radio interference to other users, the antenna type and its gain should be so chosen that the equivalent isotropically radiated power (e.i.r.p.) is not more than that permitted for successful communication.
- and must not be co-located or operating in conjunction with any other antenna or transmitterThis device has been designed to operate with the power levels shown in section 10.2 with the antennas listed in Table 2, and having a maximum gain of 2.1 dBi. Antennas not included in this list or having a gain greater than 2.1 dBi are strictly prohibited for use with this device. The required antenna impedance is 50 ohms.

#### French Statements

- Conformément à la réglementation d'Industrie Canada, le présent émetteur radio peut fonctionner avec une antenne d'un type et d'un gain maximal (ou inférieur) approuvé pour l'émetteur par Industrie Canada. Dans le but de réduire les risques de brouillage radioélectrique à l'intention des autres utilisateurs, il faut choisir le type d'antenne et son gain de sorte que la puissance isotrope rayonnée équivalente (p.i.r.e.) ne dépasse pas l'intensité nécessaire à l'établissement d'une communication satisfaisante.
- Le présent appareil est conforme aux CNR d'Industrie Canada applicables aux appareils radio exempts de licence. L'exploitation est autorisée aux deux conditions suivantes : (1) l'appareil ne doit pas produire de brouillage, et (2) l'utilisateur de l'appareil doit accepter tout brouillage radioélectrique subi, même si le brouillage est susceptible d'en compromettre le fonctionnement.



#### OEM Responsibilities

The ETRX358x and ETRX358x families of module have been certified for integration into products only by OEM integrators under the following condition:

1. The transmitter module must not be co-located or operating in conjunction with any other antenna or transmitter.

As long as the condition above is met, further transmitter testing will not be required. However, the OEM integrator is still responsible for testing their end-product for any additional compliance requirements required with this module installed (for example, digital device emissions, PC peripheral requirements, etc.).

**IMPORTANT NOTE:** In the event that these conditions can not be met (for certain configurations or co-location with another transmitter), then Industry Canada certification is no longer considered valid and the IC Certification Number can not be used on the final product. In these circumstances, the OEM integrator will be responsible for re-evaluating the end product (including the transmitter) and obtaining a separate Industry Canada authorization.

#### 2.2.1 IC Labelling Requirements

The ETRX358x and ETRX358xHR family modules are labelled with its own IC Certification Number. If the IC Certification Number is not visible when the module is installed inside another device, then the outside of the device into which the module is installed must also display a label referring to the enclosed module. In that case, the final end product must be labelled in a visible area with the following:

"Contains Transmitter Module IC: 8735A-EM358X"

or

"Contains IC: 8735A-EM358X"

The OEM of the ETRX358x and ETRX358xHR family modules must only use the approved antenna(s) listed above, which have been certified with this module.

The OEM integrator has to be aware not to provide information to the end user regarding how to install or remove this RF module or change RF related parameters in the user's manual of the end product.

The user's manual for the end product must include the following information in a prominent location:

"To comply with Industry Canada RF radiation exposure limits for general population, the transmitter must not be co-located or operating in conjunction with any other antenna or transmitter."

## 2.3 European Certification (ETSI)

The ETRX358x and ETRX358xHR families with the power settings defined in section 10.2 are tested to be compliant to the following standards:



Radio: EN 300 328:V1.9.1
 EMC: EN 301 489-17:V2.2.1

Safety: EN 60950-1:2006 / A12:2011

If the ETRX358x and ETRX358xHR families of modules are incorporated into an OEM product, the OEM product manufacturer must ensure compliance of the final product to the European Harmonised EMC, and low voltage/safety standards. A Declaration of Conformity must be issued for each of these standards and kept on file as described in Annex II of the R&TTE Directive. The final product must not exceed the specified power ratings, antenna specifications and installation requirements as specified in this user manual. If any of these specifications are exceeded in the final product then a submission must be made to a notified body for compliance testing to all of the required standards.

The 'CE' marking must be applied to a visible location on any OEM product. For more information please refer to <a href="http://ec.europa.eu/enterprise/faq/ce-mark.htm">http://ec.europa.eu/enterprise/faq/ce-mark.htm</a>. Customers assume full responsibility for learning and meeting the required guidelines for each country in their distribution market.



#### 2.4 Declarations of Conformity

Telegesis (UK) Ltd will issue Declarations of Conformity for all ETRX3 series ZigBee RF Modules, which cover RoHS, Radio Emissions and Safety. These documents will be available from our website or on request.

#### 2.5 IEEE 802.15.4

IEEE 802.15.4 is a standard for low data-rate, wireless networks (raw bit-rate within a radio packet of 250kbps @2.4GHz) which focuses on low cost, low duty cycle, long primary battery life applications as well as mains-powered applications. It is the basis for the open ZigBee Protocol.



## 2.6 The ZigBee Protocol

The ZigBee Protocol is a set of standards for wireless connectivity for use between any devices over short to medium distances. The specification was originally ratified in December 2004, paving the way for companies to start making low-power networks a reality.

ZigBee uses the IEEE 802.15.4 radio specification running on the 2.4GHz band, plus three additional layers for networking, security and applications. What makes the specification unique is its use of a mesh network architecture which, in bucket chain style, passes data from one node to the next until it lands at its destination. The network is self-healing and adapts its routing as link quality changes or nodes move. Furthermore, nodes can be defined as End Devices which do not act as routers, but can therefore be put into a low-power sleep state.

The enhanced version of the ZigBee standard (or ZigBee 2006) was released in December 2006, adding new features and improvements to the only global wireless communication standard enabling the development of easily deployable low-cost, low-power, monitoring and control products for homes, commercial buildings and industrial plant monitoring. In 2007 the ZigBee Alliance introduced the PRO featureset which offers advantages over earlier versions, including

- Truly self-healing mesh networking
- Messages can now travel up to 30 hops
- Source-Routing for improved point to multipoint message transmission
- Improved security including Trust-Centre link keys
- New message types and options



## 3 Module Pinout

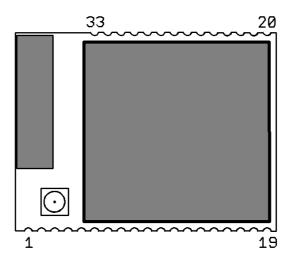


Figure 1: ETRX3 series Module Pinout (top view)

The table below gives details about the pin assignment for direct SMD soldering of the ETRX3 series modules to the application board. For more information on the alternate functions please refer to [2].

All GND pads are connected within the module, but for best RF performance all of them should be grounded externally ideally to a ground plane.

"Important Note: If designers would like to keep open the option of using either standard or long range modules in the same product please note the following. The ETRX358x series and the ETRX358x-LRS series of modules are footprint compatible, but on the ETRX358x-LRS series pins PB0 and PC5 of the EM358x are used internally to control the front-end module and are not available to the user."



ETRX358x Pad	Name	EM358x Pin	Default use	Alternate Functions
1	GND	GND	GND	
2	PC5 {1}	11		TX ACTIVE
3	PC6	13	I/O	OSC32B, nTX_ACTIVE
4	PC7	14	I/O	OSC32A, OSC32 EXT
5	PA7 {4}	18	I/O	TIM1C4
6	PB3 {2}	19	I/O, CTS	SC1nCTS, SC1SCLK, TIM2C3
7	nReset {5}	12	nReset	
8	PB4 {2}	20	I/O, RTS	TIM2C4, SC1nRTS, SC1nSSEL
9	PA0	21	I/O	TIM2C1, SC2MOSI, USBDM[6]
10	PA1	22	I/O	TIM2C3, SC2SDA, SC2MISO, USBDP{6}
11	PA2	24	I/O	TIM2C4, SC2SCL, SC2SCLK
12	PA3	25	I/O	SC2nSSEL, TIM2C2
13	GND	GND	GND	
14	PA4	26	I/O	ADC4, PTI_EN, TRACEDATA2
15	PA5 {3}	27	I/O	ADC5, PTI_DATA, nBOOTMODE, TRACEDATA3
16	PA6 {4}	29	I/O	TIM1C3
17	PB1	30	TXD	SC1MISO, SC1MOSI, SC1SDA, SC1TXD, TIM2C1
18	PB2	31	RXD	SC1MISO, SC1MOSI, SC1SCL, SC1RXD, TIM2C2
19	GND	GND	GND	
20	GND	GND	GND	
21	JTCK	32		SWCLK
22	PC2	33	I/O	JTDO, SWO, TRACEDATA0
23	PC3	34	I/O	JTDI, TRACECLK
24	PC4	35	I/O	JTMS, SWDIO
25	PB0	36	I/O, IRQ	VREF, IRQA, TRACEDATA2, TIM1CLK, TIM2MSK
26	PC1	38	I/O	ADC3, TRACEDATA3
27	PC0 {4}	40	I/O	JRST, IRQD, TRACEDATA1
28	PB7 {4}	41	I/O	ADC2, IRQC, TIM1C2
29	PB6 {4}	42	I/O	ADC1, IRQB, TIM1C1
30	PB5	43	I/O	ADC0, TIM2CLK, TIM1MSK
31	GND	GND	GND	
32	Vcc	Vcc	Vcc	

**Table 3: Pin Information** 

#### Notes:

- {1} When the alternate function is selected, TX\_ACTIVE becomes an output that indicates that the EM358x radio circuit is in transmit mode. PC5 is not usable on the long range version of the ETRX358x as this GPIO is used internally as TX\_ACTIVE to control the external RF frontend.
- {2} The serial UART connections TXD, RXD, CTS and RTS are PB1, PB2, PB3 and PB4 respectively
- {3} If PA5 is driven low at power-up or reset the module will boot up in the bootloader
- {4} PA6, PA7, PB6, PB7 and PC0 can drive high current (see section 8)
- {5} nRESET is level-sensitive, not edge-sensitive. The module is held in the reset state while nRESET is low.
- {6} ETRX3588, ETRX3586, ETRX3582 and ETRX3588HR, ETRX3586HR, ETRX3582HR variants only

See also the table "Module pads and functions" in the ETRX357 Development Kit Product Manual. Refer to the Silicon Labs EM358x manual for details of the alternate functions and pin names.



## 4 Hardware Description

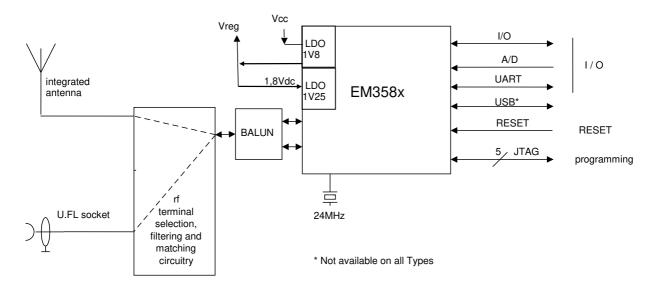


Figure 2: Hardware Diagram

The ETRX358x and ETRX358xHR families are based on the Silicon Labs EM358x family of ZigBee SoCs. The EM358x and EM358xHR are fully integrated 2.4GHz ZigBee transceivers with a 32-bit ARM<sup>®</sup> Cortex M3<sup>™</sup> microprocessor, flash and RAM memory, and peripherals.

The industry standard serial wire and JTAG programming and debugging interfaces together with the standard ARM system debug components help to streamline any custom software development.

In addition to this a number of MAC functions are also implemented in hardware to help maintaining the strict timing requirements imposed by the ZigBee and IEEE802.15.4 standards.

The new advanced power management features allow faster wakeup from sleep and new power down modes allowing this 4<sup>th</sup> generation module to offer a longer battery life than any 1<sup>st</sup> and 2<sup>nd</sup> generation modules on the market.

The EM358x modules have fully integrated voltage regulators for both required 1.8V and 1.25V supply voltages. The voltages are monitored (brown-out detection) and the built in power-on-reset circuit eliminates the need for any external monitoring circuitry. An optional 32.768 kHz watch crystal can be connected externally to pads 3 and 4 in case more accurate timing is required. To utilize the external watch crystal custom firmware is required.

#### 4.1 Hardware Interface

All GPIO pins of the EM358x chips are accessible on the module's pads. Whether signals are used as general purpose I/Os, or assigned to a peripheral function like ADC is set by the firmware. When developing custom firmware please refer to the EM358x datasheet [2].



# 5 Firmware Description

By default, the modules will be pre-loaded with a standalone bootloader which supports over-the-air bootloading as well as serial bootloading of new firmware.

In order to enter the standalone bootloader using a hardware trigger pull PA5 to ground and power-cycle or reset the module. To avoid entering the standalone bootloader unintentionally make sure not to pull this pin down during boot-up unless the resistance to ground is >10k $\Omega$ . (A pull-up is not required).

Each module comes with a unique 64-bit 802.15.4 identifier which is stored in non-volatile memory. A router is typically a mains powered device whilst a sleepy end device (SED) can be battery powered.

The module is also able to act as a coordinator and Trust Centre through external host control.



## 5.1 Token Settings

The ETRX358x Series Modules' manufacturing tokens will be pre-programmed with the settings shown in the table below.

Token	Description	TG Default
MFG_CIB_OBS	Option Bytes	<not written=""></not>
MFG_CUSTOM_VERSION	Optional Version Number	<not written=""></not>
MFG_CUSTOM_EUI_64	Custom EUI	<not written=""></not>
MFG_STRING	Device Specific String	TELEGESIS
MFG_BOARD_NAME	Hardware Identifier	<order code=""></order>
MFG_MANUF_ID	Manufacturer ID	0x1010
MFG_PHY_CONFIG	Default Power Settings	0xFF26
MFG_BOOTLOAD_AES_KEY	Bootloader Key	<not written=""></not>
MFG_EZSP_STORAGE	EZSP related	<not written=""></not>
MFG_CBKE_DATA	SE Security	<not written=""></not>
MFG_INSTALLATION_CODE	SE Installation	<not written=""></not>
MFG_OSC24M_BIAS_TRIM	Crystal Bias	<not written=""></not>
MFG_SYNTH_FREQ_OFFSET	Frequency offset	<not written=""></not>
MFG_OSC24M_SETTLE_DELAY	Crystal Stabilizing Time	<not written=""></not>
MFG_SECURITY_CONFIG	Security Settings	<not written=""></not>
MFG_CCA_THRESHOLD	CCA Threshold	<not written=""></not>
MFG_SECURE_BOOTLOADER_KEY	Secure Bootloader Key	<not written=""></not>

Table 4. Manufacturing tokens

## 5.2 Custom Firmware

The ETRX358x series of modules is an ideal platform for developing custom firmware. In order to develop custom firmware the Silicon Labs Ember toolchain is required.



# 6 Absolute Maximum Ratings

No.	Item	Symbol	Absolute Maximum Ratings	Unit
1	Supply voltage	Vcc	-0.3 to +3.6	Vdc
2	Voltage on any Pad	Vin	-0.3 to V <sub>CC</sub> +0.3	Vdc
3	Voltage on any Pad pin (PA4, PA5, PB5, PB6, PB7, PC1), when used as an input to the general purpose ADC with the low voltage range selected	Vin	-0.3 to +2.0	Vdc
4	Module storage temperature range	T <sub>stg</sub>	-40 to +105	°C
5	Reel storage temperature range	T <sub>stgreel</sub>	0 to 75	°C
6	Operating temperature range	Top	-40 to +85	°C
7	Input RF level	P <sub>max</sub>	15	dBm
8	Reflow temperature	T <sub>Death</sub>	Please refer to chapter 12	°C

**Table 5: Absolute Maximum Ratings** 

The absolute maximum ratings given above should under no circumstances be violated. Exceeding one or more of the limiting values may cause permanent damage to the device.



Caution! ESD sensitive device. Precautions should be used when handling the device in order to prevent permanent damage.

## 6.1 Environmental Characteristics

No.	Item	Symbol	Absolute Maximum Ratings	Unit
1	ESD on any pad according to Human Body Model (HBM) circuit description	Vтннвм	±2	kV
2	ESD on non-RF pads according to Charged Device Model (CDM) circuit description	Vтнсом	±400	V
3	ESD on RF terminal according to Charged Device Model (CDM) circuit description	Vтнсом	±225	V
4	Moisture Sensitivity Level	MSL	MSL3, per J-STD-033	

**Table 6: Absolute Maximum Ratings** 

## 6.2 Recommended Operating Conditions

No.	Item	Condition / Remark	Symbol	Value			Unit
				Min	Тур	Max	
1	Supply voltage		Vcc	2.1		3.6	Vdc
2	RF Input Frequency		fc	2405		2480	MHz
3	RF Input Power		рім			0	dBm
4	Operating temperature range		Тор	-40		+85	°C

**Table 7: Recommended Operating Conditions** 



# 7 DC Electrical Characteristics

 $V_{\text{CC}}$  = 3.0V,  $T_{\text{AMB}}$  = 25°C, NORMAL MODE (non-Boost) unless otherwise stated

No.	Item	Condition / Remark	Symbol		Value		Unit
				Min	Тур	Max	
1	Module supply voltage		Vcc	2.1		3.6	Vdc
Deep	Sleep Current						
2	Quiescent current, internal RC oscillator disabled,	4kB RAM retained	ISLEEP		1.0		μΑ
3	Quiescent current, internal RC oscillator enabled	4kB RAM retained	ISLEEP		1.25		μΑ
4	Quiescent current, including 32.768kHz oscillator	4kB RAM retained	I <sub>SLEEP</sub>		1.6		μΑ
5	Quiescent current including internal RC oscillator and 32.768kHz oscillator	4kB RAM retained	I <sub>SLEEP</sub>		1.9		μΑ
6	Additional current per 4kB block of RAM retained		I <sub>RAMSLEEP</sub>		0,067		μΑ
Reset	Current						
7	Quiescent current		I <sub>RESET</sub>		2	3	mA
Droop	nReset asserted ssor and Peripheral Current	•					
	ARM® Cortex <sup>TM</sup> M3,	25°C, 12MHz					
8	RAM and flash memory	Core clock	Імси		7.5		mA
9	ARM <sup>®</sup> Cortex <sup>™</sup> M3, RAM and flash memory	25°C, 24MHz Core clock	Імси		8.5		mA
10	ARM <sup>®</sup> Cortex <sup>™</sup> M3, RAM and flash memory sleep current	25°C, 12MHz Core clock	Імси		4.0		mA
11	ARM® Cortex <sup>TM</sup> M3, RAM and flash memory sleep current	25°C, 6MHz Core clock	Імси		2.5		mA
12	Serial controller current	Per serial controller at max. clock rate	Isc		0.2		mA
13	General purpose timer current	Per timer at max. clock rate	I <sub>TIM</sub>		0.25		mA
14	General purpose ADC current	Max. Sample rate, DMA	I <sub>ADC</sub>		1.1		mA
15	USB Active Current		lusb		1		mA
16	USB Suspend Mode Current		IUSBSUSP			2.5	mA
RX Cı							
17	Radio receiver MAC and Baseband	ARM <sup>®</sup> Cortex <sup>™</sup> M3 sleeping.	I <sub>RX</sub>		23.5		mA
18	Receive current consumption	Total, 12MHz clock speed	I <sub>RX</sub>		27		mA
19	Receive current consumption	Total, 24MHz clock speed	I <sub>RX</sub>		28		mA
20	Receive current consumption BOOST MODE	Total, 12MHz clock speed	I <sub>RX</sub>		29		mA
21	Receive current consumption BOOST MODE	Total, 24MHz clock speed	I <sub>RX</sub>		30		mA



TX Cu	rrent				
22	Transmit current consumption	at +3dBm module output power, CPU at 12MHz	I <sub>TXVCC</sub>	31.5	mA
23	Transmit Current consumption BOOST MODE	at +8dBm module output power, CPU at 12MHz	Ітхусс	44	mA
24	Transmit current consumption	at +0dBm module output power, CPU at 12MHz	Ітхусс	29	mA
25	Transmit current consumption	at min. module output power, CPU at 12MHz	Ітхусс	24	mA
26	Transmit current consumption	at +8dBm module output power, CPU at 24MHz	Ітхусс	45	mA
26	Wake time from deep sleep	From wakeup event to 1 <sup>st</sup> instruction		110	μs
27	Shutdown time	From last instruction into deep sleep		5	μs

**Table 8: DC Electrical Characteristics** 

<u>Please Note:</u> The average current consumption during operation is dependent on the firmware and the network load.



# 8 Digital I/O Specifications

The digital I/Os of the ETRX35x module

 $V_{CC} = 3.0V$ ,  $T_{AMB} = 25$ °C, NORMAL MODE unless otherwise stated

No.	Item	Condition / Remark	Sympol value		Value		Unit
				Min	Тур	Max	
1	Low Schmitt switching threshold	Schmitt input threshold going from high to low	V <sub>SWIL</sub>	0.42 x V <sub>CC</sub>		0.5 x V <sub>CC</sub>	Vdc
2	High Schmitt switching threshold	Schmitt input threshold going from low to high	VswiH	0.62 x V <sub>CC</sub>		0.8 x V <sub>CC</sub>	Vdc
3	Input current for logic 0		Iı∟			-0.5	μΑ
4	Input current for logic 1		Іін			0.5	μΑ
5	Input Pull-up resistor value		RIPU	24	29	34	kΩ
6	Input Pull-down resistor value		R <sub>IPD</sub>	24	29	34	kΩ
7	Output voltage for logic 0	I <sub>OL</sub> = 4mA (8mA) for standard (high current) pads	V <sub>OL</sub>	0		0.18 x V <sub>CC</sub>	V
8	Output voltage for logic 1	I <sub>OH</sub> = 4mA (8mA)for standard (high current) pads	V <sub>OH</sub>	0.82 x V <sub>CC</sub>		Vcc	V
9	Output Source Current	Standard current pad	I <sub>OHS</sub>			4	mA
10	Output Sink current	Standard current pad	lous			4	mA
11	Output Source Current	High current pad (1)	Іонн			8	mA
12	Output Sink current	High current pad (1)	I <sub>OLH</sub>			8	mA
13	Total output current		IOH + IOL			40	mA

Table 9. Digital I/O Specifications

No.	Item	Condition / Remark	Symbol	Value		Unit	
				Min	Тур	Max	
1	Low Schmitt switching threshold	Schmitt input threshold going from high to low	V <sub>SWIL</sub>	0.42 x V <sub>CC</sub>		0.5 x V <sub>CC</sub>	Vdc
2	High Schmitt switching threshold	Schmitt input threshold going from low to high	Vswih	0.62 x V <sub>CC</sub>		0.68 x V <sub>CC</sub>	Vdc
3	Input current for logic 0		I₁∟			-0.5	μΑ
4	Input current for logic 1		Іін			0.5	μΑ
5	Input Pull-up resistor value	Chip not reset	RIPU	24	29	34	kΩ
6	Input Pull-up resistor value	Chip reset	RIPURESET	12	14.5	17	kΩ

Table 10. nReset Pin Specifications

#### **Notes**

1) High current pads are PA6, PA7, PB6, PB7, PC0



# 9 A/D Converter Characteristics

The ADC is a first-order sigma-delta converter. For additional information on the ADC please refer to the EM358x datasheet.

No.	Item	
1	A/D resolution	Up to 14 bits
2	A/D sample time for 7-bit conversion	5.33µs (188kHz)
3	A/D sample time for 14-bit conversion	682μs
4	Reference Voltage	1.2V

Table 11. A/D Converter Characteristics

## 10 AC Electrical Characteristics

 $V_{CC}$  = 3.0V,  $T_{AMB}$  = 25°C, NORMAL MODE measured at  $50\Omega$  terminal load connected to the U.FL socket

No.	D. Receiver		Value	Unit	
		Min	Тур	Max	
1	Frequency range	2400		2500	MHz
2	Sensitivity for 1% Packet Error Rate (PER)		-100	-94	dBm
3	Sensitivity for 1% Packet Error Rate (PER) BOOST MODE		-102	-96	dBm
4	Saturation (maximum input level for correct operation)	0			dBm
5	High-Side Adjacent Channel Rejection (1% PER and desired signal –82dBm acc. to [1])		35		dB
6	Low-Side Adjacent Channel Rejection (1% PER and desired signal –82dBm acc. to [1])		35		dB
7	2 <sup>nd</sup> High-Side Adjacent Channel Rejection (1% PER and desired signal –82dBm acc. to [1])		46		dB
8	2 <sup>nd</sup> Low-Side Adjacent Channel Rejection (1% PER and desired signal –82dBm acc. to [1])		46		dB
9	Channel Rejection for all other channels (1% PER and desired signal –82dBm acc. to [1])		40		dB
10	802.11g rejection centred at +12MHz or -13MHz (1% PER and desired signal -82dBm acc. to [1])		36		dB
11	Co-channel rejection (1% PER and desired signal –82dBm acc. to [1])		-6		dBc
12	Relative frequency error (2x40ppm required by [1])	-120		120	ppm
13	Relative timing error (2x40ppm required by [1])	-120		120	ppm
14	Linear RSSI range	40			dB
15	Output power at highest power setting NORMAL MODE BOOST MODE	0	3 8		dBm
16	Output power at lowest power setting		-55		dBm
17	Error vector magnitude as per IEEE802.15.4		5	15	%
18	Carrier frequency error	-40		40	ppm
19	PSD mask relative 3.5MHz distance from carrier	-20			dB
20	PSD mask absolute 3.5MHz distance from carrier	-30			dBm

**Table 12. RF Electrical Characteristics** 



**Please Note:** For the relationship between EM358x power settings and module output power please relate to chapter 10.1 of this document. When developing custom firmware the output power settings described in this document relate directly to the EM358x power settings accessible via the Ember stack API.

No.	No. Synthesiser Characteristics		Limit	Unit	
		Min	Тур	Max	
22	Frequency range	2400		2500	MHz
23	Frequency resolution		11.7		kHz
24	Lock time from off state, with correct VCO DAC settings			100	μs
25	Relock time, channel change or Rx/Tx turnaround			100	μs
26	Phase noise at 100kHz offset		-75dBc/Hz		
27	Phase noise at 1MHz offset		-100dBc/Hz		
28	Phase noise at 4MHz offset		-108dBc/Hz		
29	Phase noise at 10MHz offset		-114dBc/Hz		

**Table 13: Synthesiser Characteristics** 

No.	Power On Reset (POR) Specifications	Limit		Unit	
		Min	Тур	Max	
30	Vcc POR release	0.62	0.95	1.2	Vdc
31	V <sub>CC</sub> POR assert	0.45	0.65	0.85	Vdc

**Table 14: Power On Reset Specifications** 

No.	nRESET Specifications	Limit		Unit	
		Min	Тур	Max	
32	Reset Filter Time constant	2.1	12	16	μs
33	Reset Pulse width to guarantee a reset	26			μs
34	Reset Pulse width guaranteed not to cause reset	0		1	μs

Table 15: nReset Specifications



#### 10.1 TX Power Characteristics

The diagrams below show the typical output power and module current in dependency on module EM3588 power setting. Power settings above 3dBm have Boost Mode enabled. Please note that the output power is independent of the supply voltage as the radio is supplied by an internally regulated voltage.

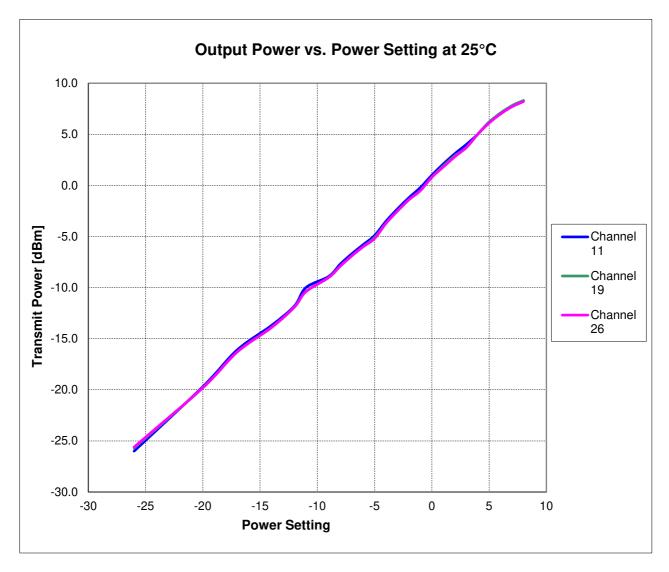


Figure 3: Output Power vs. Power Setting (BOOST mode activated from Power setting of 4 upwards)



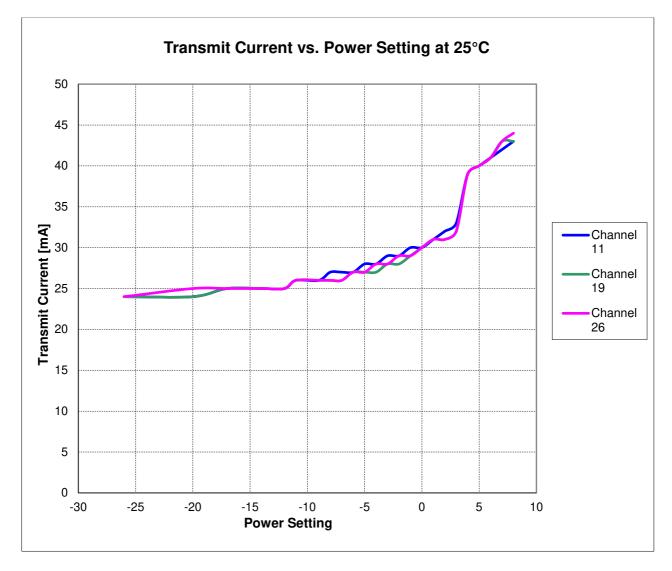


Figure 4: Module Current vs. Power Setting (BOOST mode activated from Power setting of 4 upwards)



## 10.2 Power Settings for Regulatory Compliance

Due to national restrictions the maximum power levels of the ETRX358x and ETRX358xHR family of modules need to be adjusted as shown in the tables below. The default power setting of the EmberZNet stack is +3dBm.

Antenna	Channels 11-18	Channels 19-24	Channel 25	Channel 26
1/2 Wave	8dBm boost	8dBm boost	8dBm boost	8dBm boost
1/4 Wave	8dBm boost	8dBm boost	8dBm boost	8dBm boost
On Board	8dBm boost	8dBm boost	8dBm boost	8dBm boost

**Table 10: Maximum Power Settings for European Compliance** 

Finally Table 11 lists the maximum Power settings for FCC, IC and C-Tick compliance.

Antenna	Channels 11-18	Channels 19-24	Channel 25	Channel 26
1/2 Wave	8dBm boost	8dBm boost	7dBm boost	-8dBm normal
1/4 Wave	8dBm boost	8dBm boost	7dBm boost	-8dB normal
On Board	8dBm boost	8dBm boost	7dBm boost	-8dB normal

Table 11: Maximum Power Settings for FCC, IC Compliance



# 11 Physical Dimensions

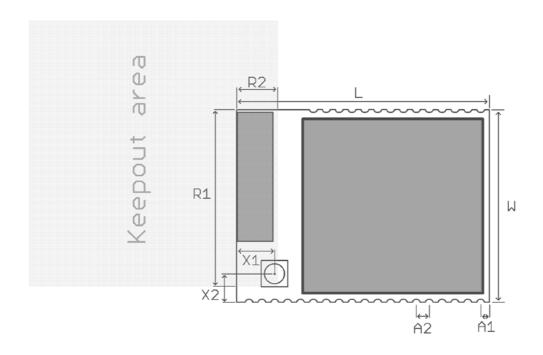


Figure 5: ETRX3 Physical Dimensions

Symbol	Explanation	Typical Distance
L	Length of the module	25.0mm
W	Width of the module	19.0mm
Н	Height of the module	3.8mm
A1	Distance centre of pad PCB edge	0.9mm
A2	Pitch	1.27mm
R1	Keep-out Zone from corner of PCB	17.5mm
R2	Keep-out Zone from corner of PCB	4.1mm
X1	Distance centre of Antenna connector PCB edge	3.8mm
X2	Distance centre of Antenna connector PCB edge	2.8mm

**Table 12: ETRX3 Physical Dimensions** 

For ideal RF performance when using the on-board antenna, the antenna should be located at the corner of the carrier PCB. There should be no components, tracks or copper planes in the keep-out area which should be as large as possible. When using the U.FL RF connector the keep-out area does not have to be obeyed. **Note**: The modules' transmit/receive range will depend on the antenna used and also the housing of the finished product.